#### **Triacs**

### **Silicon Bidirectional Thyristors**

Designed primarily for full-wave ac control applications, such as light dimmers, motor controls, heating controls and power supplies.

#### **Features**

- Blocking Voltage 400 V
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- High Surge Current Capability 60 A Peak at  $T_C = 80^{\circ}C$
- Pb-Free Package is Available

#### **MAXIMUM RATINGS** (T<sub>J</sub> = 25°C unless otherwise noted)

| Rating  | Symbol                                | Value       | Unit             |
|---|---------------------------------------|-------------|------------------|
| Peak Repetitive Off–State Voltage (Note 1)<br>(Sine Wave 50 to 60 Hz,<br>T <sub>J</sub> = -40 to +100°C, Gate Open) | V <sub>DRM,</sub><br>V <sub>RRM</sub> | 400         | ٧                |
| On–State RMS Current (T <sub>C</sub> = +80°C)<br>(Full Cycle Sine Wave 50 to 60 Hz)                                 | I <sub>T(RMS)</sub>                   | 6.0         | Α                |
| Peak Non-repetitive Surge Current (One Full Cycle, 60 Hz, T <sub>C</sub> = +80°C)                                   | I <sub>TSM</sub>                      | 60          | Α                |
| Circuit Fusing Considerations (t = 8.3 ms)  | l <sup>2</sup> t                      | 15          | A <sup>2</sup> s |
| Peak Gate Power<br>(T <sub>C</sub> = +80°C, Pulse Width = 10 μsec)  | P <sub>GM</sub>                       | 16          | W                |
| Average Gate Power (T <sub>C</sub> = +80°C, t = 8.3 ms)   | $P_{G(AV)}$                           | 0.2         | W                |
| Peak Gate Current (Pulse Width = 10 μsec)   | $I_{GM}$                              | 4.0         | Α                |
| Operating Junction Temperature Range  | TJ                                    | -40 to +125 | °C               |
| Storage Temperature Range   | T <sub>stg</sub>                      | -40 to +150 | °C               |

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol          | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction-to-Case  | $R_{\theta JC}$ | 2.7 | °C/W |
| Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds | T <sub>L</sub>  | 260 | °C   |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

 V<sub>DRM</sub>, V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

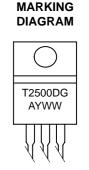


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# TRIACS 6 AMPERES RMS 400 VOLTS







= Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

| PIN ASSIGNMENT |                 |  |  |  |
|----------------|-----------------|--|--|--|
| 1              | Main Terminal 1 |  |  |  |
| 2              | Main Terminal 2 |  |  |  |
| 3              | Gate            |  |  |  |
| 4              | Main Terminal 2 |  |  |  |

#### ORDERING INFORMATION

| Device  | Package              | Shipping        |
|---------|----------------------|-----------------|
| T2500D  | TO220AB              | 500 Units / Box |
| T2500DG | TO220AB<br>(Pb-Free) | 500 Units / Box |

#### T2500D

#### $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_C = 25^{\circ}\text{C unless otherwise noted}; \ \text{Electricals apply in both directions})$

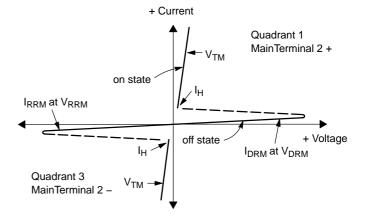
| Characteristic  | Symbol                                 | Min | Тур      | Max       | Unit     |
|---|--|-----|----------|-----------|----------|
| OFF CHARACTERISTICS   | •                                      |     | •        |           |          |
| Peak Repetitive Blocking Current T <sub>J</sub> = 25°C<br>(Rated V <sub>DRM</sub> , V <sub>RRM</sub> ; Gate Open) T <sub>J</sub> = 100°C                    | I <sub>DRM</sub> ,<br>I <sub>RRM</sub> | -   | _        | 10<br>2.0 | μA<br>mA |
| ON CHARACTERISTICS  |  |     |          |           |          |
| Peak On-State Voltage (Note 2)<br>(I <sub>TM</sub> = ±30 A Peak)  | V <sub>TM</sub>                        | -   | _        | 2.0       | V        |
| Gate Trigger Current (Continuous dc) $ (V_D = 12 \text{ Vdc}, R_L = 100 \Omega) $   | I <sub>GT</sub>                        |     |          |           | mA       |
| MT2(+), G(+) MT2(+), G(-)   |  | -   | 10<br>20 | 25<br>60  |          |
| MT2(-), G(-)<br>MT2(-), G(+)  |  | -   | 15<br>30 | 25<br>60  |          |
| Gate Trigger Voltage (Continuous dc) (All Four Quadrants) (V <sub>D</sub> = 12 Vdc, R <sub>L</sub> = 100 $\Omega$ )   | V <sub>GT</sub>                        | -   | 1.25     | 2.5       | V        |
| Gate Non–Trigger Voltage $(V_D = 12 \text{ V}, \text{ R}_L = 100 \Omega, \text{ T}_C = 100^{\circ}\text{C})$  | $V_{GD}$                               | 0.2 | -        | _         | V        |
| Holding Current (Main Terminal Voltage = 12 Vdc, Gate Open, Initiating Current = ±200 mA)   | I <sub>H</sub>                         | -   | 15       | 30        | mA       |
| Gate Controlled Turn-On Time (Rated $V_{DRM}$ , $I_T$ = 10 A , $I_{GT}$ = 160 mA, Rise Time = 0.1 $\mu$ s)  | t <sub>gt</sub>                        | -   | 1.6      | _         | μS       |
| DYNAMIC CHARACTERISTICS   |  |     |          |           |          |
| Critical Rate-of-Rise of Commutation Voltage (Rated $V_{DRM}$ , $I_{T(RMS)} = 6$ A, Commutating di/dt = 3.2 A/ms, Gate Unenergized, $T_{C} = 80^{\circ}C$ ) | dv/dt(c)                               | _   | 10       | _         | V/μs     |
| Critical Rate-of-Rise of Off-State Voltage<br>(Rated V <sub>DRM</sub> , Exponential Voltage Rise, Gate Open, T <sub>C</sub> = 100°C)                        | dv/dt                                  | -   | 75       | _         | V/μs     |

Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

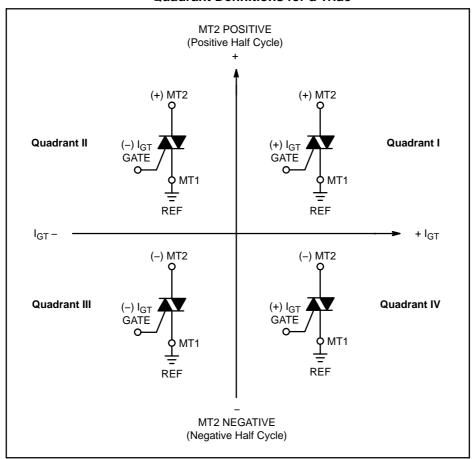
#### T2500D

## Voltage Current Characteristic of Triacs (Bidirectional Device)

|                  | T   |
|------------------|---|
| Symbol           | Parameter                                 |
| V <sub>DRM</sub> | Peak Repetitive Forward Off State Voltage |
| I <sub>DRM</sub> | Peak Forward Blocking Current             |
| V <sub>RRM</sub> | Peak Repetitive Reverse Off State Voltage |
| I <sub>RRM</sub> | Peak Reverse Blocking Current             |
| V <sub>TM</sub>  | Maximum On State Voltage                  |
| I <sub>H</sub>   | Holding Current                           |



#### **Quadrant Definitions for a Triac**



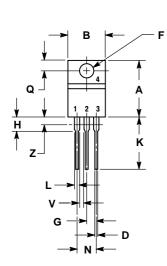
All polarities are referenced to MT1.

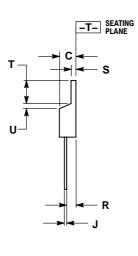
With in-phase signals (using standard AC lines) quadrants I and III are used.

#### T2500D

#### PACKAGE DIMENSIONS

#### TO-220 **CASE 221A-07 ISSUE AA**





- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 114.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION Z DEFINES A ZONE WHERE ALL
  BODY AND LEAD IRREGULARITIES ARE
  ALLOWED.

|     | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
| DIM | MIN    | MAX   | MIN         | MAX   |
| Α   | 0.570  | 0.620 | 14.48       | 15.75 |
| В   | 0.380  | 0.405 | 9.66        | 10.28 |
| С   | 0.160  | 0.190 | 4.07        | 4.82  |
| D   | 0.025  | 0.035 | 0.64        | 0.88  |
| F   | 0.142  | 0.147 | 3.61        | 3.73  |
| G   | 0.095  | 0.105 | 2.42        | 2.66  |
| Н   | 0.110  | 0.155 | 2.80        | 3.93  |
| J   | 0.014  | 0.022 | 0.36        | 0.55  |
| K   | 0.500  | 0.562 | 12.70       | 14.27 |
| L   | 0.045  | 0.060 | 1.15        | 1.52  |
| N   | 0.190  | 0.210 | 4.83        | 5.33  |
| Q   | 0.100  | 0.120 | 2.54        | 3.04  |
| R   | 0.080  | 0.110 | 2.04        | 2.79  |
| S   | 0.045  | 0.055 | 1.15        | 1.39  |
| T   | 0.235  | 0.255 | 5.97        | 6.47  |
| U   | 0.000  | 0.050 | 0.00        | 1.27  |
| ٧   | 0.045  |       | 1.15        |       |
| Z   |        | 0.080 |             | 2.04  |

- PIN 1. MAIN TERMINAL 1
  - 2. MAIN TERMINAL 2
  - 3. GATE
  - 4. MAIN TERMINAL 2

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